Absolute Maximum Ratings * T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	160	V
V _{CBO}	Collector-Base Voltage	180	V
V _{EBO}	Emitter-Base Voltage	6.0	V
Ι _C	Collector current - Continuous	600	mA
T _J , T _{stg}	Junction and Storage Temperature	-55 to +150 °C	

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired. NOTES:

1. These ratings are based on a maximum junction temperature of 150 degrees C.

2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Мах		Units	
		2N5551	*MMBT5551	Units	
PD	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	m₩ m₩/°C	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	83.3		°C/W	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	200	357	°C/W	

* Device mounted on FR-4 PCB 1.6" \times 1.6" \times 0.06."

© 2009 Fairchild Semiconductor Corporation 2N5551 / MMBT5551 Rev. B1 2N5551 / MMBT5551 — NPN General Purpose Amplifier

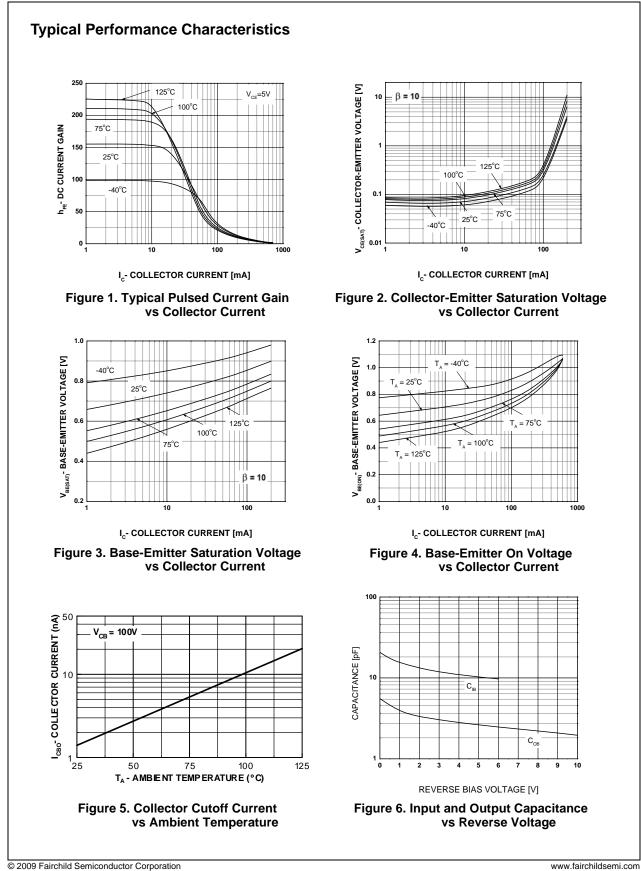
2N5551 / MMBT5551 — NPN General Purpose Amplifier

Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charac	cteristics		•		•
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$	160		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$	180		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 {\rm uA}, I_{\rm C} = 0$	6.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 120V, I_E = 0$ $V_{CB} = 120V, I_E = 0, T_A = 100^{\circ}C$		50 50	nA μA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 4.0 V, I_{C} = 0$		50	nA
On Charac	teristics	•			
h _{FE}	DC Current Gain	$\begin{split} I_{C} &= 1.0 \text{mA}, \ V_{CE} = 5.0 \text{V} \\ I_{C} &= 10 \text{mA}, \ V_{CE} = 5.0 \text{V} \\ I_{C} &= 50 \text{mA}, \ V_{CE} = 5.0 \text{V} \end{split}$	80 80 30	250	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{C} = 10$ mA, $I_{B} = 1.0$ mA $I_{C} = 50$ mA, $I_{B} = 5.0$ mA		0.15 0.20	V V
V _{BE(sat)}	Base-Emitter On Voltage	$I_{C} = 10$ mA, $I_{B} = 1.0$ mA $I_{C} = 50$ mA, $I_{B} = 5.0$ mA		1.0 1.0	V V
Small Sigr	nal Characteristics	•			
f _T	Current Gain Bandwidth Product	$I_{C} = 10$ mA, $V_{CE} = 10$ V, f = 100MHz	100		MHz
C _{obo}	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 1.0MHz$		6.0	pF
C _{ibo}	Input Capacitance	$V_{BE} = 0.5V, I_{C} = 0, f = 1.0MHz$		20	pF
H _{fe}	Small-Signal Current Gain	$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ kHz}$	50	250	
NF	Noise Figure	I_{C} = 250 uA, V _{CE} = 5.0 V, R _S =1.0 kΩ, f=10 Hz to 15.7 kHz		8.0	dB

Spice Model

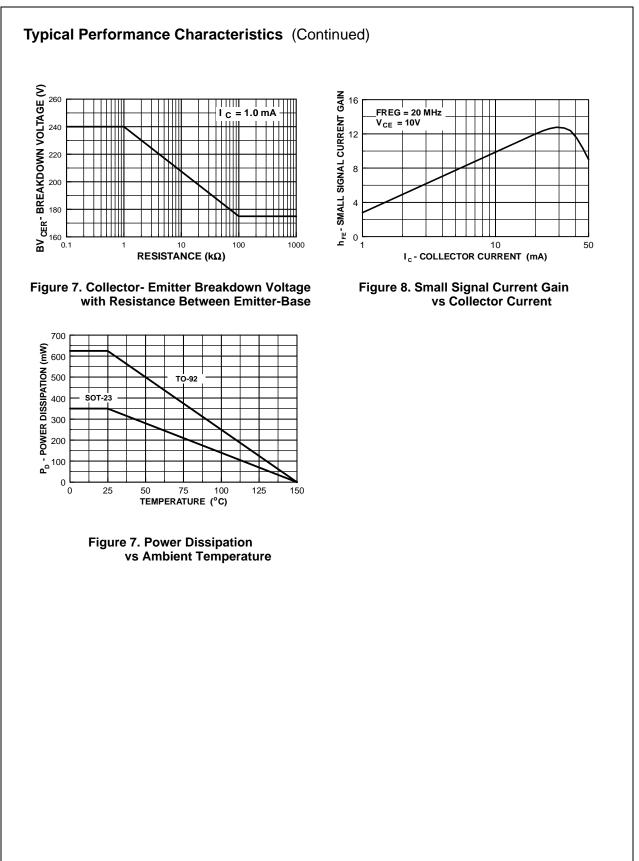
NPN (Is=2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 Ne=1.249 Ise=2.511f Ikf=.3458 Xtb=1.5 Br=3.197 Nc=2 Isc=0 Ikr=0 Rc=1 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc=.5 Cje=18.79p Mje=.3416 Vje=.75 Tr=1.202n Tf=560p Itf=50m Vtf=5 Xtf=8 Rb=10)



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2N5551 / MMBT5551 Rev. B1

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